

NPN TRIPLE DIFFUSED  
PLANAR SILICON TRANSISTOR

KSD5070

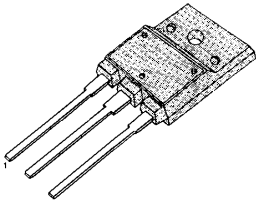
COLOR TV HORIZONTAL OUTPUT  
APPLICATION (DAMPER DIODE BUILT IN)

- High Collector-Base Voltage ( $V_{CBO}=1500V$ )
- High Switching Speed ( $t_F$ . max=0.4uS)

ABSOLUTE MAXIMUM RATING

Characteristic	Symbol	Rating	Unit
Collector-Base Voltage	$V_{CBO}$	1500	V
Collector-Emitter Voltage	$V_{CEO}$	800	V
Emitter-Base Voltage	$V_{EBO}$	6	V
Collector Current (DC)	$I_C$	2.5	A
Collector Current (Pulse)	$I_C$	10	A
Collector Dissipation ( $T_C=25^{\circ}C$ )	$P_C$	50	W
Junction Temperature	$T_J$	150	$^{\circ}C$
Storage Temperature	$T_{STG}$	-55 ~ 150	$^{\circ}C$

TO-3PF

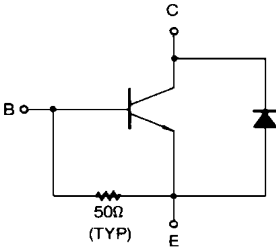


1.Base 2.Collector 3.Emitter

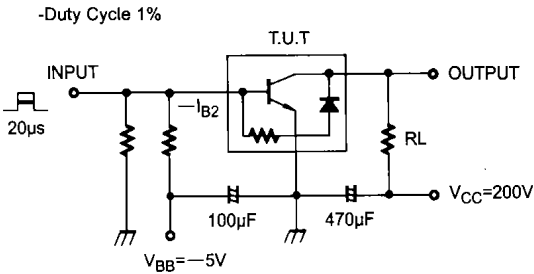
ELECTRICAL CHARACTERISTICS ( $T_C=25^{\circ}C$ )

Characteristic	Symbol	Test Condition	Min	Typ	Max	Unit
Collector Cutoff Current	$I_{CBO}$	$V_{CB} = 800V, I_E = 0$			10	$\mu A$
Emitter Cutoff Current	$I_{EBO}$	$V_{EB} = 4V, I_C = 0$	40		200	mA
DC Current Gain	$h_{FE}$	$V_{CE} = 5V, I_C = 0.5A$	8			
Collector Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 2A, I_B = 0.6A$			8	V
Base Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = 2A, I_B = 0.6A$			1.5	V
Current Gain Bandwidth Product	$f_T$	$V_{CE} = 10V, I_C = 0.5A$		3		MHz
Damper Diode Turn On Voltage	$V_F$	$I_F = 2.5A$			2	V
Fall Time	$t_F$	$I_C = 2A, I_{B1} = 0.6A$ $I_{B2} = -1.2A, V_{CC} = 200V$ $R_L = 100\Omega$			0.4	$\mu s$

-EQUIVALENT CIRCUIT



-SWITCHING TIME TEST CIRCUIT



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Rev B.

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